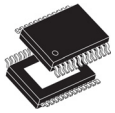
VNI4140K-32

Quad high-side smart power solid-state relay

Datasheet - production data



PowerSSO-24

Features

Type	V_{demag} (1)	$R_{DS(on)}$ (1)	I_{out} (1)	V_{CC}
VNI4140K-32	V_{CC}-41 V	0.08 Ω	1 A	41 V

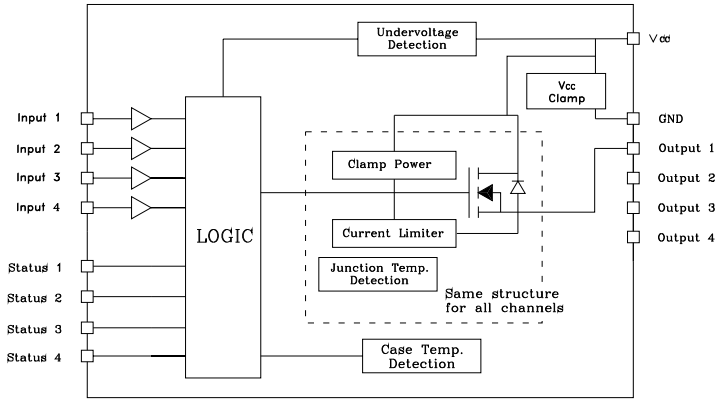
1. Per channel

- Output current: 1 A per channel
- Shorted load protections
- Junction overtemperature protection
- Case overtemperature protection for thermal independence of the channels
- Thermal case shutdown restart not simultaneous for the various channels
- Protection against loss of ground
- Current limitation
- Undervoltage shutdown
- Open drain diagnostic outputs
- 3.3 V CMOS/TTL compatible inputs
- Fast demagnetization of inductive loads
- Conforms to IEC 61131-2
- ESD according to IEC 61000-4-2 up to +/- 25 KV

Description

The VNI4140K-32 is a monolithic device made using STMicroelectronics VIPower technology, intended to drive four independent resistive, capacitive or inductive loads with one side connected to ground. Active current limitation avoids the system power supply dropping in case of shorted load. Built-in thermal shutdown protects the chip from overtemperature and short-circuit. In overload conditions, the channel turns OFF and back ON automatically so to maintain junction temperature between T_{TSD} and T_R. If this condition causes case temperature to reach T_{CSD}, the overloaded channel is turned OFF and restarts only when case temperature has decreased down to T_{CR}. In case of more than one channel in overload, restart of the overloaded channels is not simultaneous, in order to avoid high peak current from the supply. Non-overloaded channels continue operating normally. The open drain diagnostic outputs indicate overtemperature conditions.

Figure 1. Block diagram



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1 Pin connection

Figure 2. Pin connection (top view)

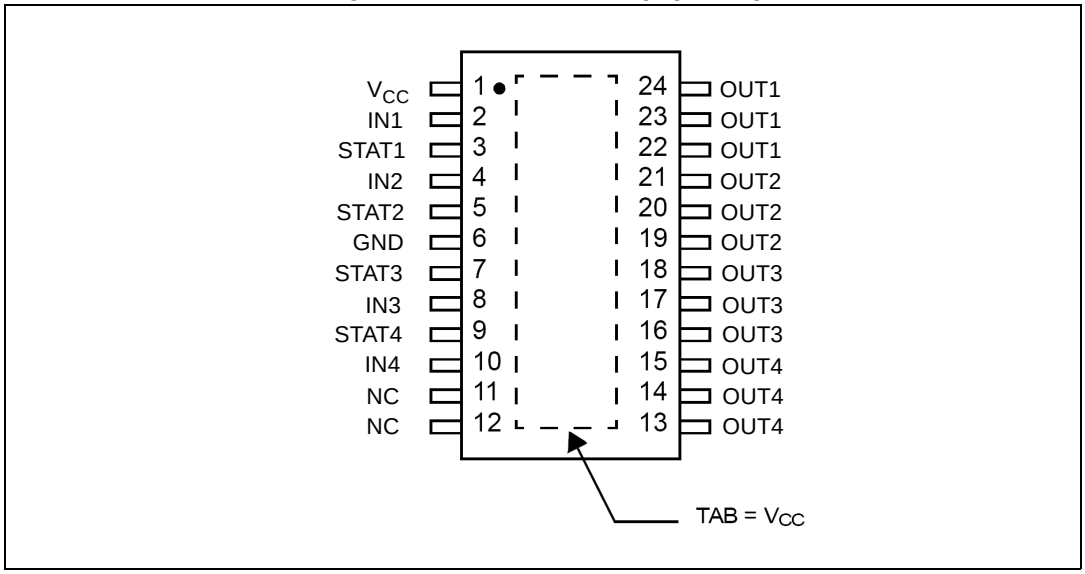


Table 1. Pin description

Pin	Name	Description
Tab	TAB	Exposed tab internally connected to V_{cc}
1	V_{CC}	Supply voltage
2	IN1	Channel 1 input 3.3 V CMOS/TTL compatible
3	STAT1	Channel 1 status in open drain configuration
4	IN2	Channel 2 input 3.3 V CMOS/TTL compatible
5	STA2	Channel 2 status in open drain configuration
6	GND	Device ground connection
7	STAT3	Channel 3 status in open drain configuration
8	IN3	Channel 3 input 3.3 V CMOS/TTL compatible
9	STAT4	Channel 4 status in open drain configuration
10	IN4	Channel 4 input 3.3 V CMOS/TTL compatible
11	NC	
12	NC	
13	OUT4	Channel 4 power stage output, internally protected
14	OUT4	Channel 4 power stage output, internally protected
15	OUT4	Channel 4 power stage output, internally protected
16	OUT3	Channel 3 power stage output, internally protected
17	OUT3	Channel 3 power stage output, internally protected

Table 1. Pin description (continued)

Pin	Name	Description
18	OUT3	Channel 3 power stage output, internally protected
19	OUT2	Channel 2 power stage output, internally protected
20	OUT2	Channel 2 power stage output, internally protected
21	OUT2	Channel 2 power stage output, internally protected
22	OUT1	Channel 1 power stage output, internally protected
23	OUT1	Channel 1 power stage output, internally protected
24	OUT1	Channel 1 power stage output, internally protected

2 Maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Power supply voltage	41	V
$-V_{CC}$	Reverse supply voltage	-0.3	V
I_{GND}	DC ground reverse current	-250	mA
I_{OUT}	Output current (continuous)	Internally limited	A
I_R	Reverse output current (per channel)	-5	A
I_{IN}	Input current (per channel)	± 10	mA
V_{IN}	Input voltage	$+V_{CC}$	V
V_{STAT}	Status pin voltage	$+V_{CC}$	V
I_{STAT}	Status pin current	± 10	mA
V_{ESD}	Electrostatic discharge (R = 1.5 kΩ; C = 100 pF)	2000	V
E_{AS}	I_{OUT} = 500 mA T_{AMB} = 125 °C	5	J
P_{TOT}	Power dissipation at T_c = 25 °C	Internally limited	W
T_J	Junction operating temperature	Internally limited	°C
T_{STG}	Storage temperature	-55 to 150	°C

2.1 Thermal data

Table 3. Thermal data

Symbol	Parameter		Value	Unit
$R_{th(JC)}$	Thermal resistance junction-case(1)	Max.	2	°C/W
$R_{th(JA)}$	Thermal resistance junction-ambient	Max.	see *Figure 11*	°C/W

1. Per channel.

3 Recommended

Table 4. Input switching limits

Symbol	Parameter	Value	Unit
$f_{Vin\ MAX}$	Maximum input switching frequency	10	kHz

4 Electrical characteristics

10.5 V < V_{CC} < 36 V; -40 °C < T_J < 125 °C; unless otherwise specified.

Table 5. Power section

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{cc}	Supply voltage		10.5		36	V
$R_{DS(on)}$	ON state resistance	I_{OUT} = 0.7 A at T_J = 25 °C I_{OUT} = 0.7 A			0.080 0.140	Ω Ω
V_{clamp}		I_S = 20 mA	41	45	52	V
I_S	Supply current	All channels in OFF state, ON state with V_{IN} = 5 V		250 2.4	4	µA mA
$V_{OUT(OFF)}$	OFF state output voltage	V_{IN} = 0 V and I_{OUT} = 0 A			1	V
$I_{OUT(OFF)}$	OFF state output current	V_{IN} = V_{OUT} = 0 V	0		5	µA
I_{LGND}	Output current in ground disconnection	V_{cc}= V_{IN} = GND = 24 V; T_J = 125 °C			500	µA
F_{CP}	Charge pump frequency	Channel in ON state(1)		1450		kHz

1. To cover EN55022 class A and class B normative.

V_{CC} = 24 V; -40 °C < T_J < 125 °C, R_L = 48 Ω, input rise time < 0.1 µs

Table 6. Switching

Symbol	Parameter	Min.	Typ.	Max.	Unit
$t_{d(ON)}$	Turn ON delay	-	6	-	µs
t_r	Rise time	-	5	-	µs
$t_{d(OFF)}$	Turn OFF	-	12	-	µs
t_f	Fall time	-	5	-	µs
$dV/dt_{(ON)}$	Turn ON voltage slope	-	4	-	V/µs
$dV/dt_{(OFF)}$	Turn OFF voltage slope	-	4	-	V/µs

Figure 3. Switching parameter conventions

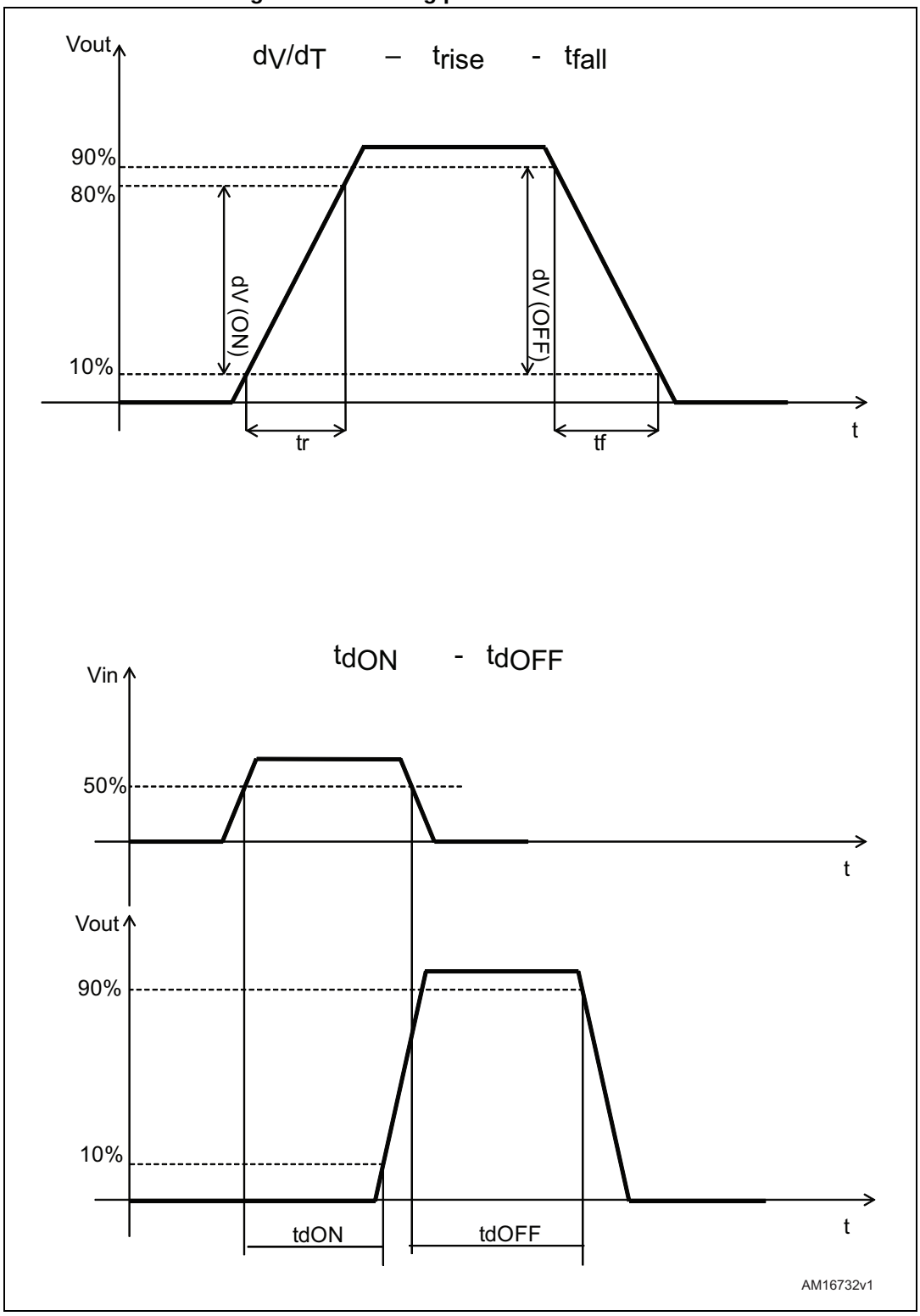


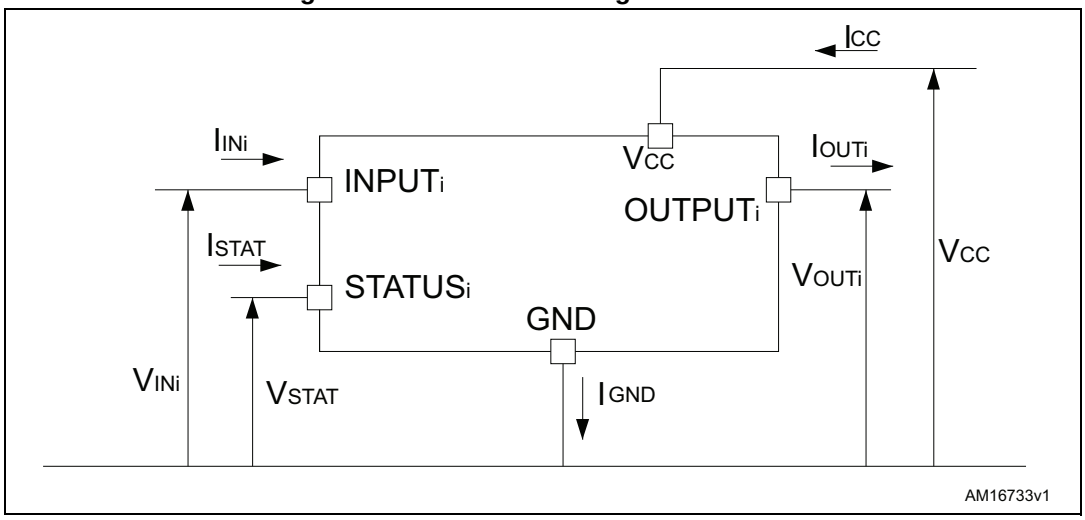
Table 7. Logical input

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IL}	Input low level voltage				0.8	V
V_{IH}	Input high level voltage		2.20			V
$V_{I(HYST)}$	Input hysteresis voltage			0.15		V
I_{IN}	Input current	V_{IN} = 15 V			10	µA
		V_{IN} = 36 V			210	

Table 8. Protection and diagnostic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
v_{STAT}	Status voltage output low	I_{STAT} = 1.6 mA			0.6	V
V_{USD}	Undervoltage protection		7		10.5	V
V_{USDHYS}	Undervoltage hysteresis		0.4	0.5		V
I_{LIM}	DC short-circuit current	V_{CC} = 24 V; R_{LOAD} < 10 mΩ	1.1		2.6	A
I_{PEAK}	Maximum DC output current	Dynamic load		1.6		A
I_{LSTAT}	Status leakage current	V_{CC} = V_{STAT} = 36 V		30		µA
T_{TSD}	Junction shutdown temperature		150	170	190	°C
T_R	Junction reset temperature		135			°C
T_{HIST}	Junction thermal hysteresis		7	15		°C
T_{CSD}	Case shutdown temperature		125	130	135	°C
T_{CR}	Case reset temperature		110			°C
T_{CHYST}	Case thermal hysteresis		7	15		°C
V_{demag}	Output voltage at turn-OFF	I_{OUT} = 0.5 A; L_{LOAD} >= 1 mH	V_{CC}-41	V_{CC}-45	V_{CC}-52	V

Figure 4. Current and voltage conventions



5 Truth table

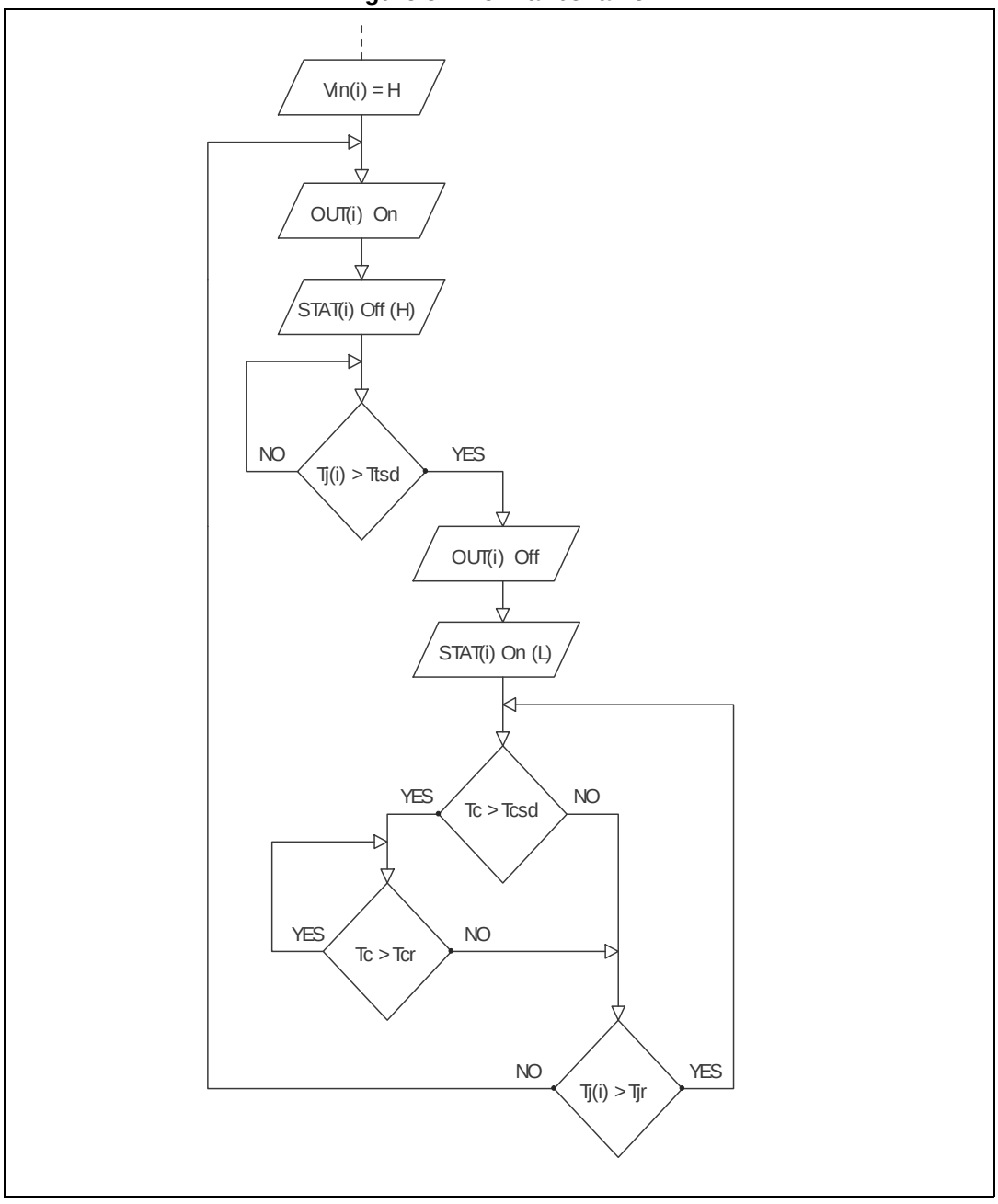
Table 9. Truth table

Conditions	INPUTn	OUTPUTn	STATUSn
Normal operation	L H	L H	H H
Overtemperature	L H	L L	H L
Undervoltage	L H	L L	X X
Shorted load (current limitation before thermal shutdown)	L H	L X	H H

6 Thermal management

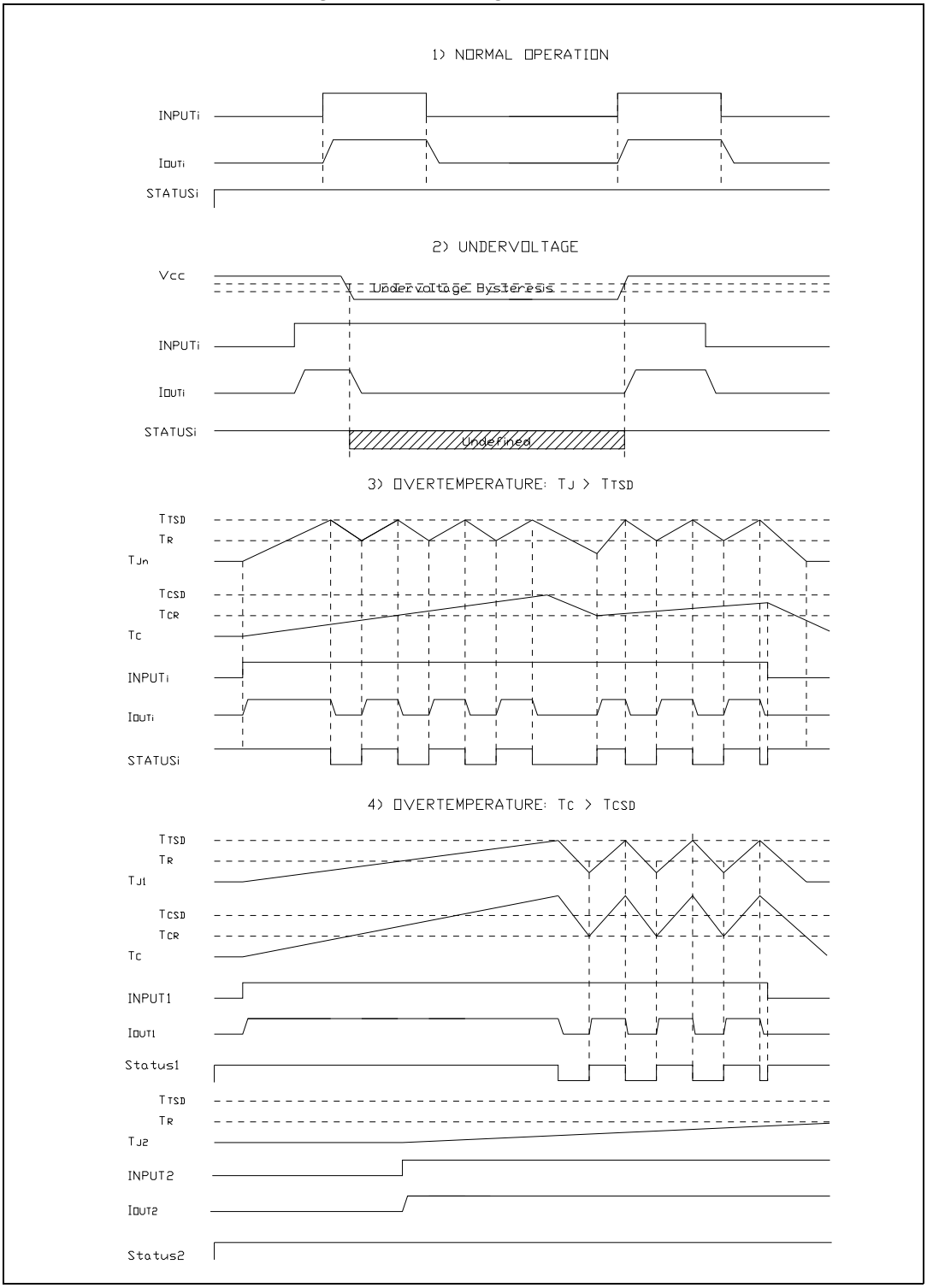
The power dissipation in the IC is the main factor that sets the safe operating condition of the device in the application. Therefore, it must be considered very carefully. Furthermore, the available space on the PCB should be chosen considering the power dissipation. Heat sinking can be achieved using copper on the PCB with proper area and thickness. Two different protections have been implemented to guarantee safety of the device if it overheats due to an overloaded condition or high environment temperature.The following flowchart explains in detail this protection functionality.

Figure 5. Thermal behavior



7 Switching waveforms

Figure 6. Switching waveforms



8 Pin functions

Figure 7. Input circuit

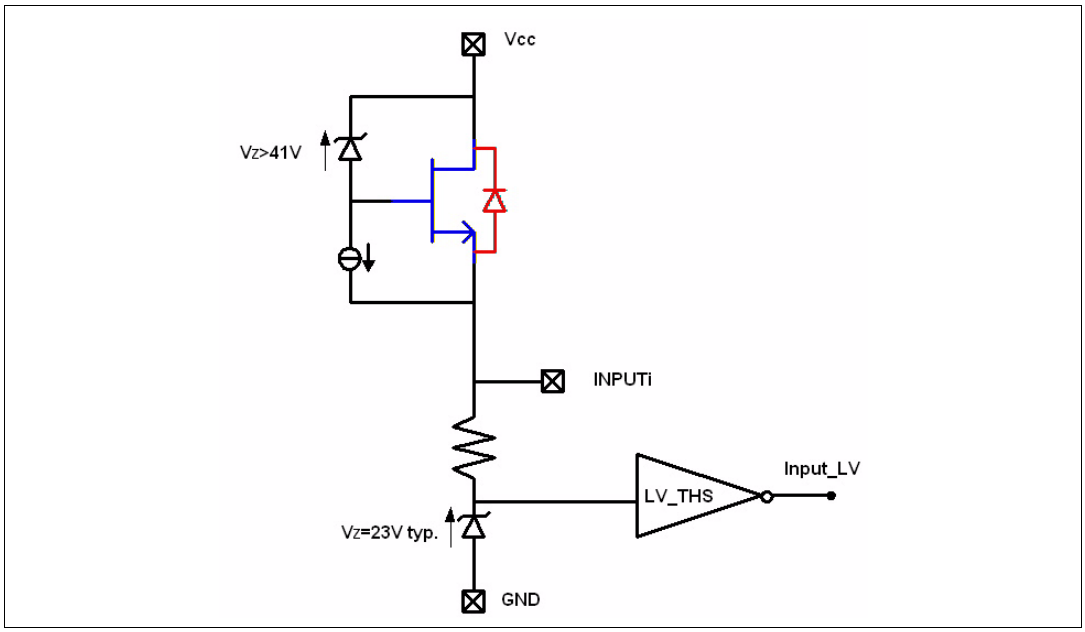


Figure 8. Status circuit

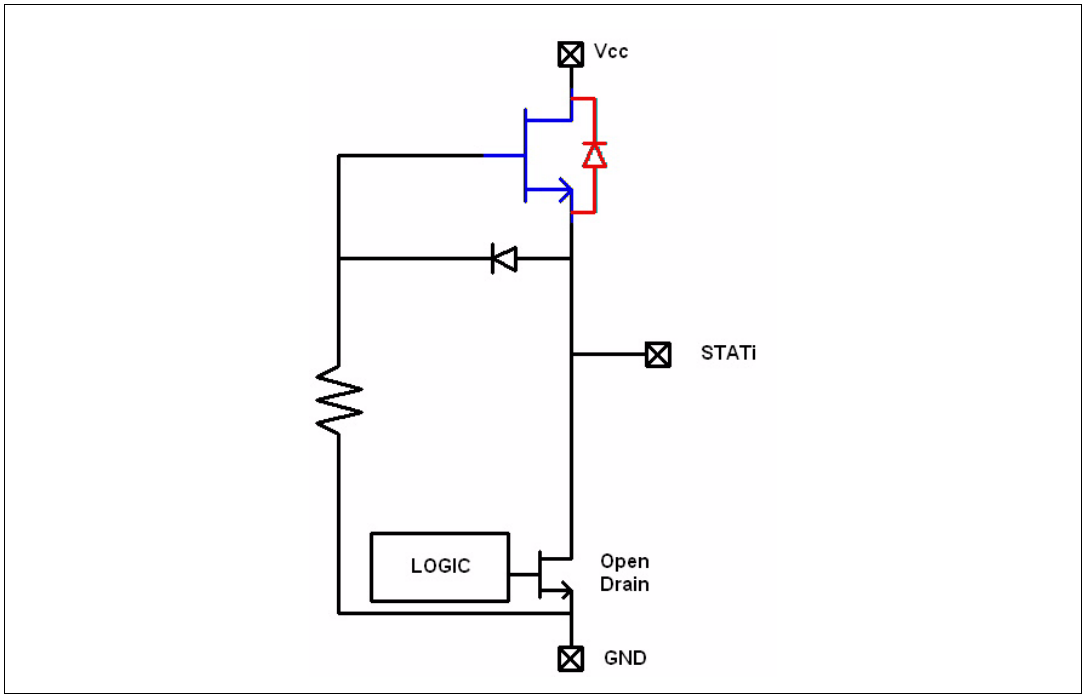
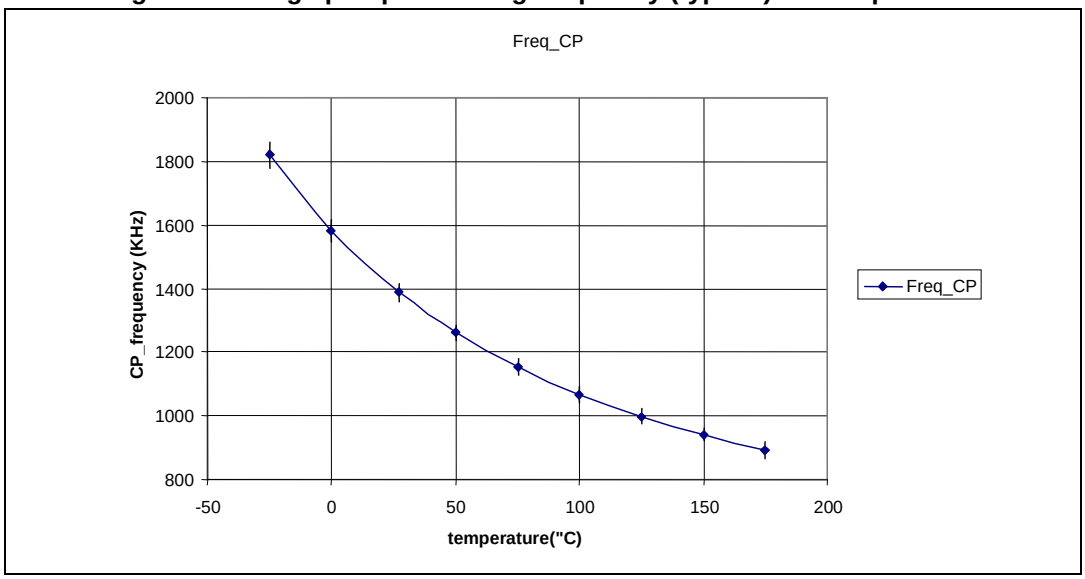


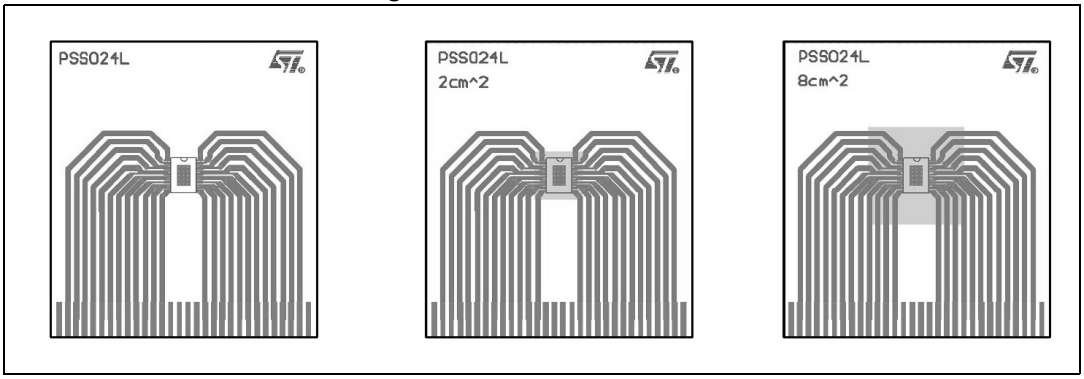
Figure 9. Charge pump switching frequency (typical) vs. temperature



9 Package and PCB thermal data

9.1 VNI4140K-32 thermal data

Figure 10. VNI4140K-32 PCB



Note: Layout condition of R_{th} and Z_{th} measurements (PCB: double layer, thermal vias, FR4 area = 77 mm x 86 mm, PCB thickness=1.6 mm, Cu thickness = 70 mm (front and back side), copper areas: from minimum pad layout to 8 cm^2).

Figure 11. $R_{th(JA)}$ vs. PCB copper area in open box free air condition (one channel ON)

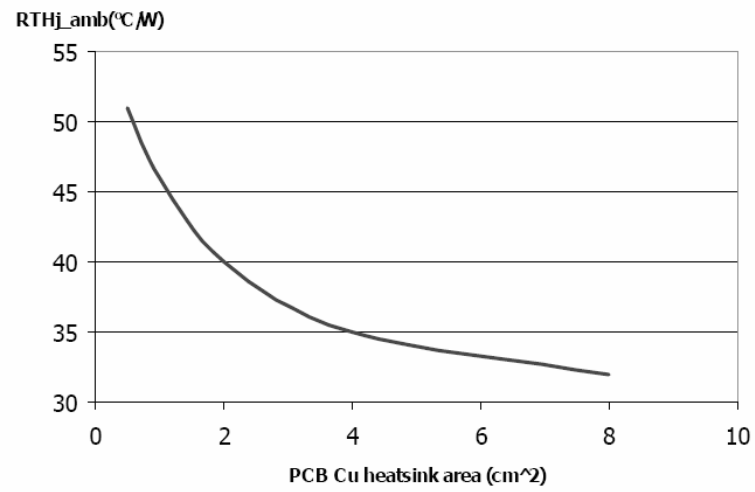
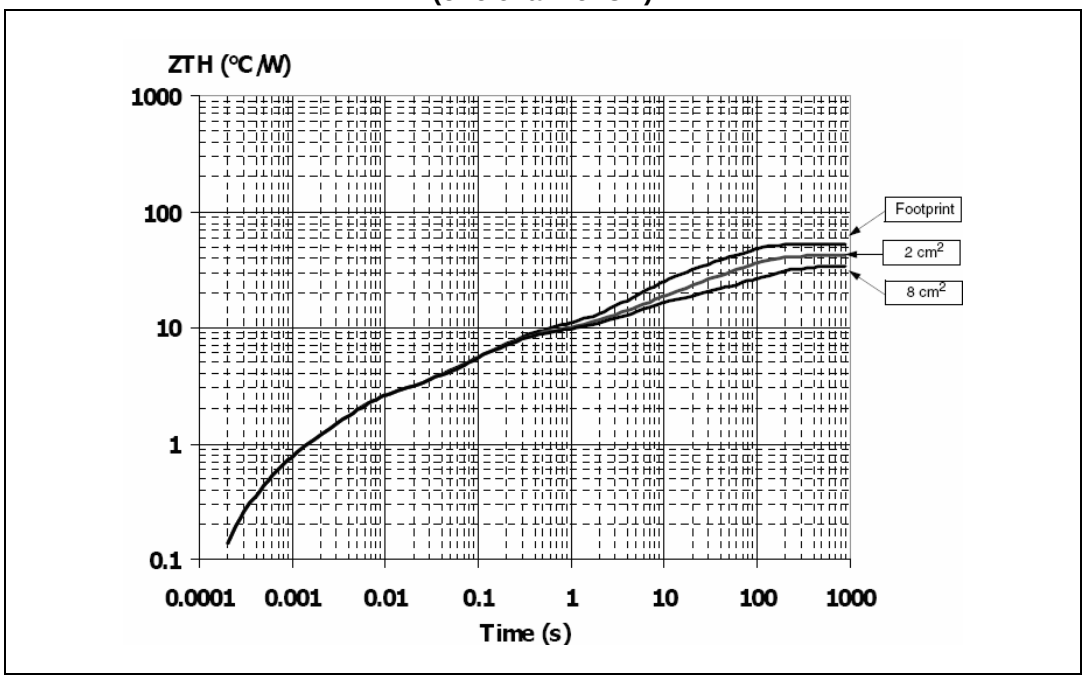


Figure 12. VNI4140K-32 thermal impedance junction-ambient single pulse (one channel ON)



10 Reverse polarity protection

Reverse polarity protection can be implemented on board using two different solutions:

1. Placing a resistor (R_{GND}) between IC GND pin and load GND
2. Placing a diode between IC GND pin and load GND

If option 1 is selected, the minimum resistance value has to be selected according to the following equation:

Equation 1

$R_{GND} \geq V_{CC} / I_{GND}$

where I_{GND} is the DC reverse ground pin current and can be found in *Section 2: Maximum ratings* of this datasheet.

Power dissipated by R_{GND} (when $V_{CC} < 0$: during reverse polarity situations) is:

Equation 2

$P_D = V_{CC}^2/R_{GND}$

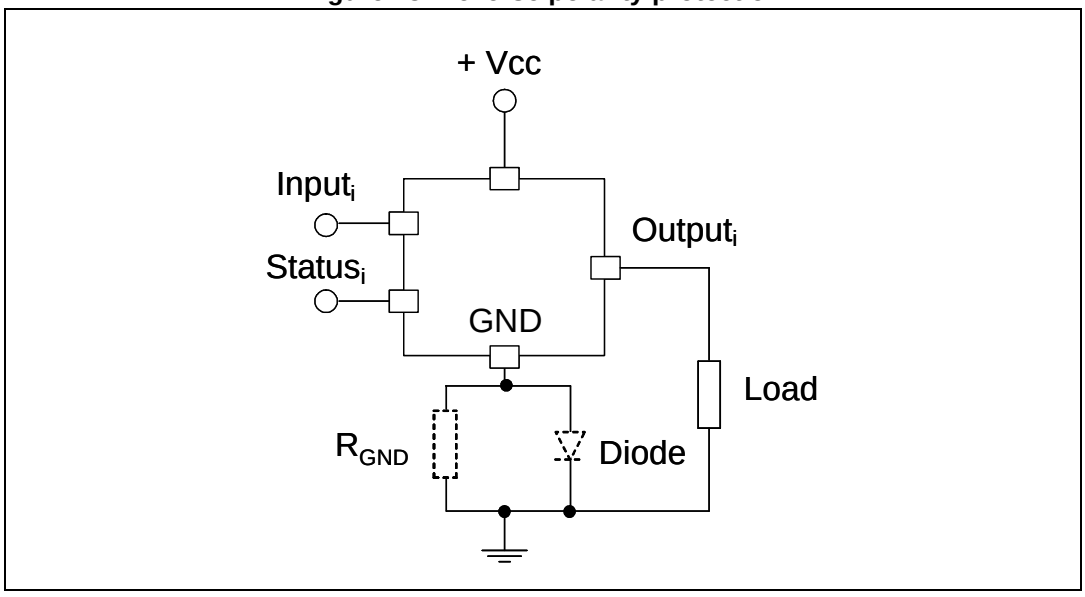
If option 2 is selected, the diode has to be chosen by taking into account VRRM >$|V_{cc}|$ and its power dissipation capability:

Equation 3

$P_D \geq I_S*V_F$

Note: In normal conditions (no reverse polarity), due to the diode, there is a voltage drop between GND of the device and GND of the system.

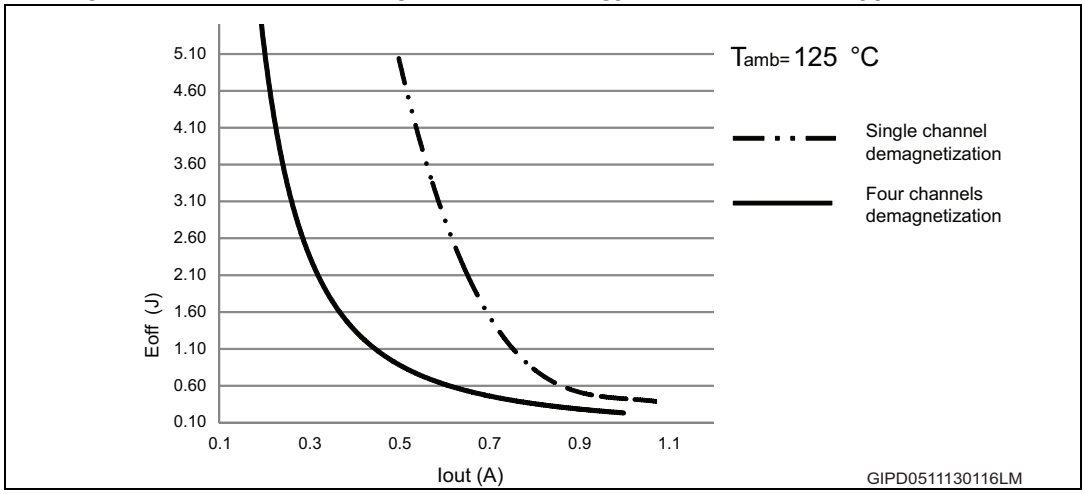
Figure 13. Reverse polarity protection



This schematic can be used with any type of load.

11 Demagnetization energy

Figure 14. Maximum demagnetization energy vs. load current, typical values



12 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at:www.st.com. ECOPACK® is an ST trademark.

Table 10. PowerSSO-24 mechanical data

Symbol	mm		
	Min.	Typ.	Max.
A	2.15		2.47
A2	2.15		2.40
a1	0		0.075
b	0.33		0.51
c	0.23		0.32
D	10.10		10.50
E	7.4		7.6
e		0.8	
e3		8.8	
G			0.1
G1			0.06
H	10.1		10.5
h			0.4
L	0.55		0.85
N			10deg
X	4.1		4.7
Y	6.5		7.1

Figure 15. PowerSSO-24 package dimensions

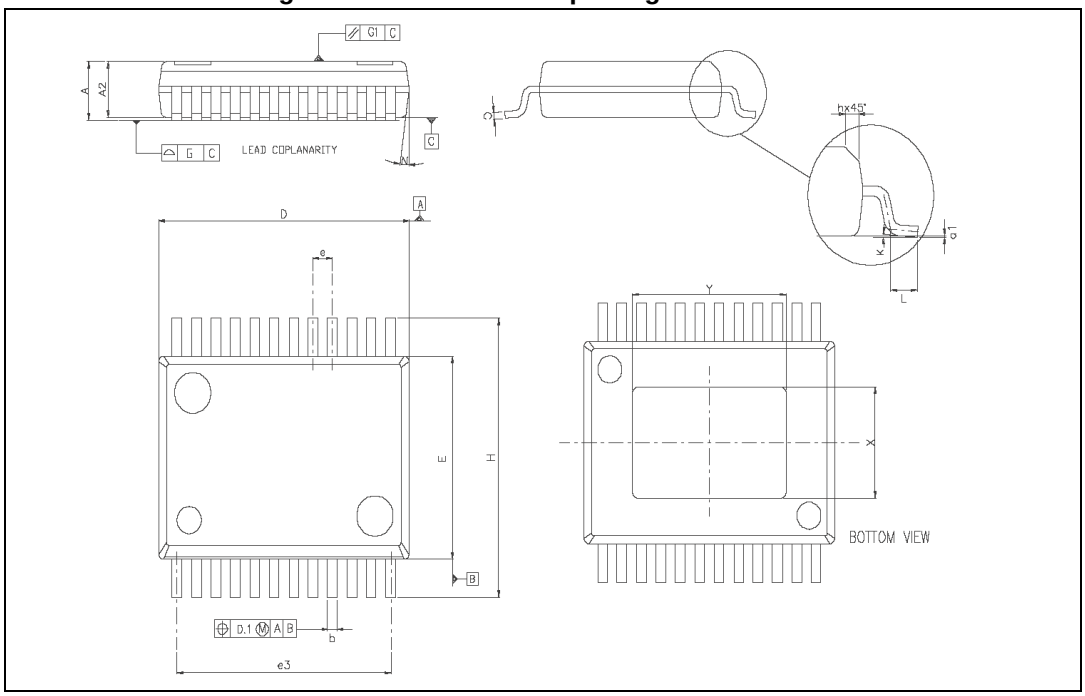


Figure 16. PowerSSO-24 tube shipment (no suffix)

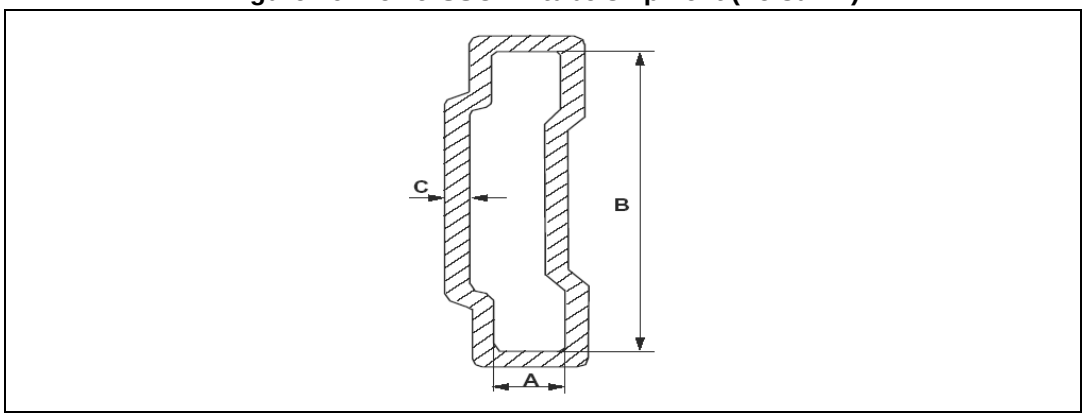


Table 11. PowerSSO-24 tube shipment

Base quantity	49
Bulk quantity	1225
Tube length (± 0.5)	532
A	3.5
B	13.8
C (± 0.1)	0.6

Note: All dimensions are in mm.

Figure 17. PowerSSO-24 reel shipment (suffix “TR”)

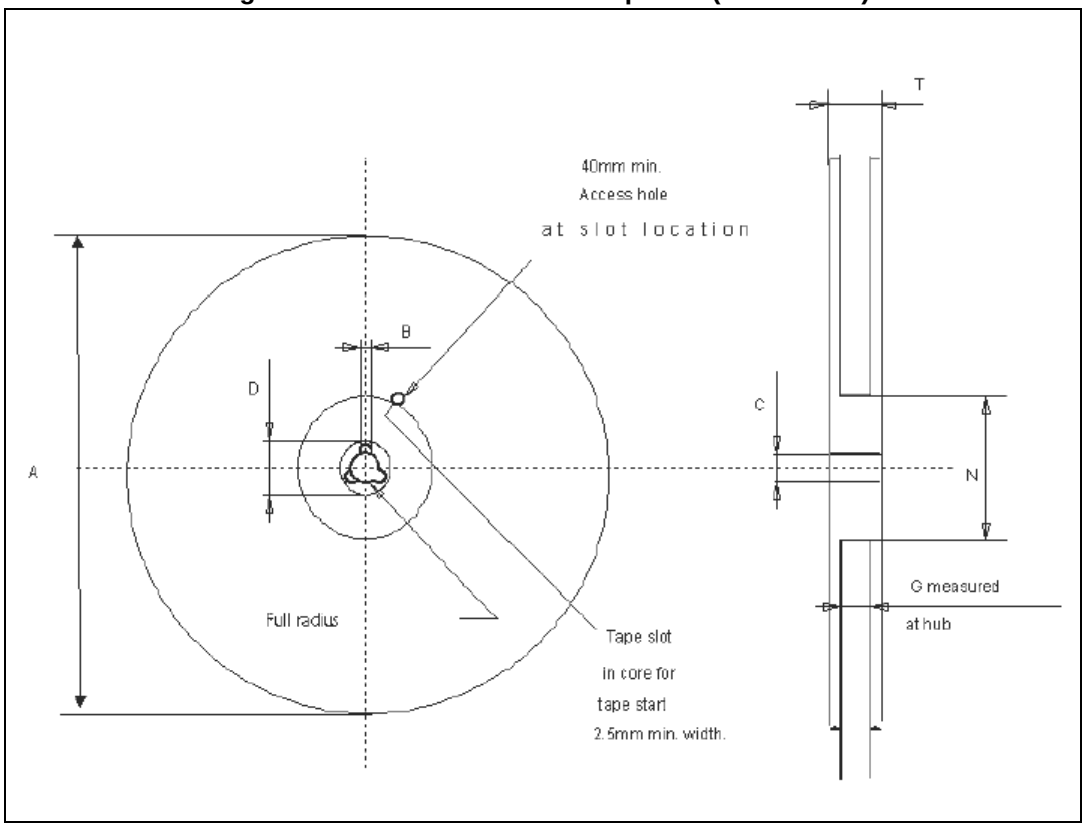


Table 12. PowerSSO-24 reel dimensions

Base quantity	1000
Bulk quantity	1000
A (max.)	330
B (min.)	1.5
C (± 0.2)	13
F	20.2
G (2 ± 0)	24.4
N (min.)	100
T (max.)	30.4

Figure 18. PowerSSO-24 tape drawings

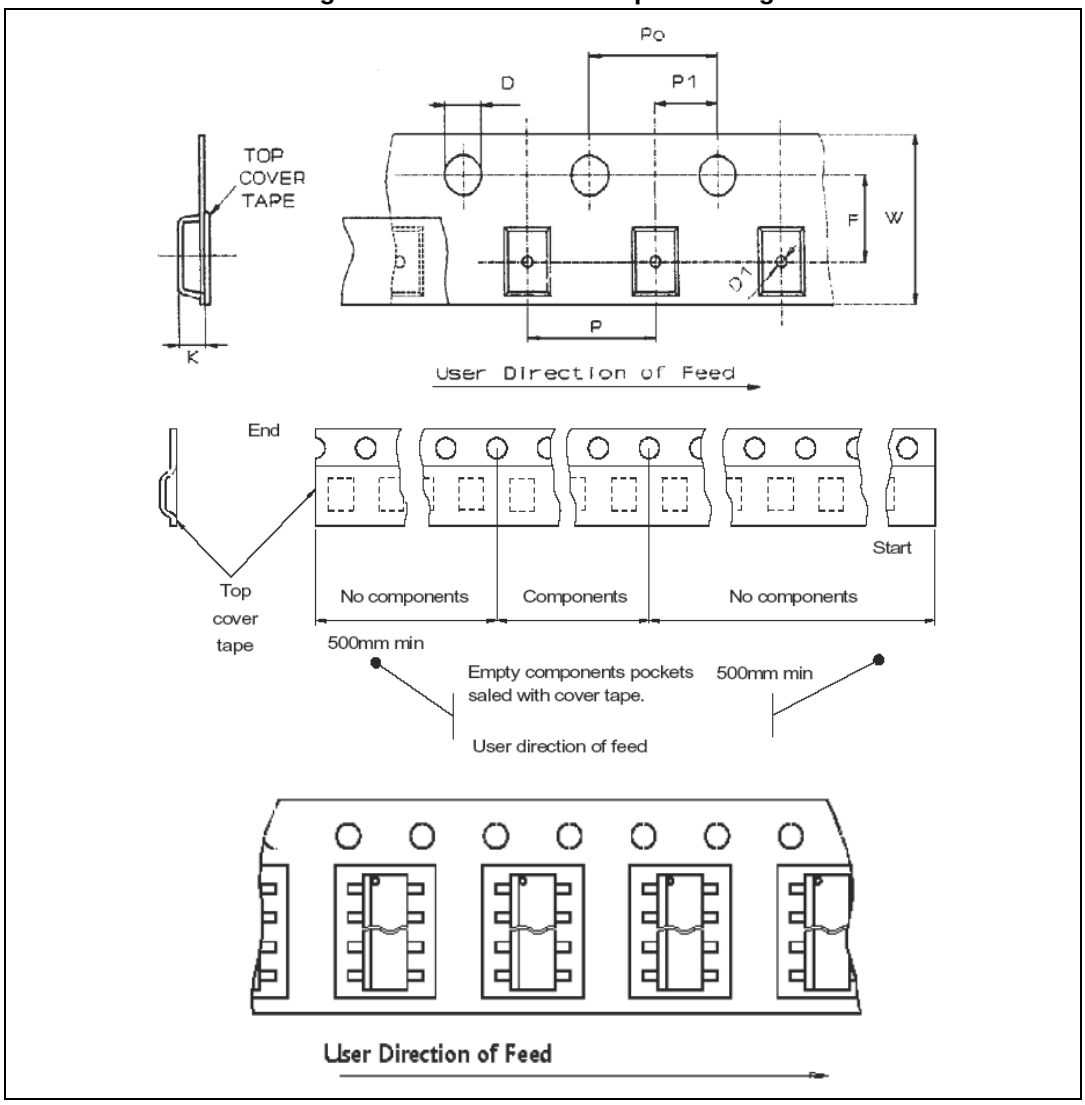
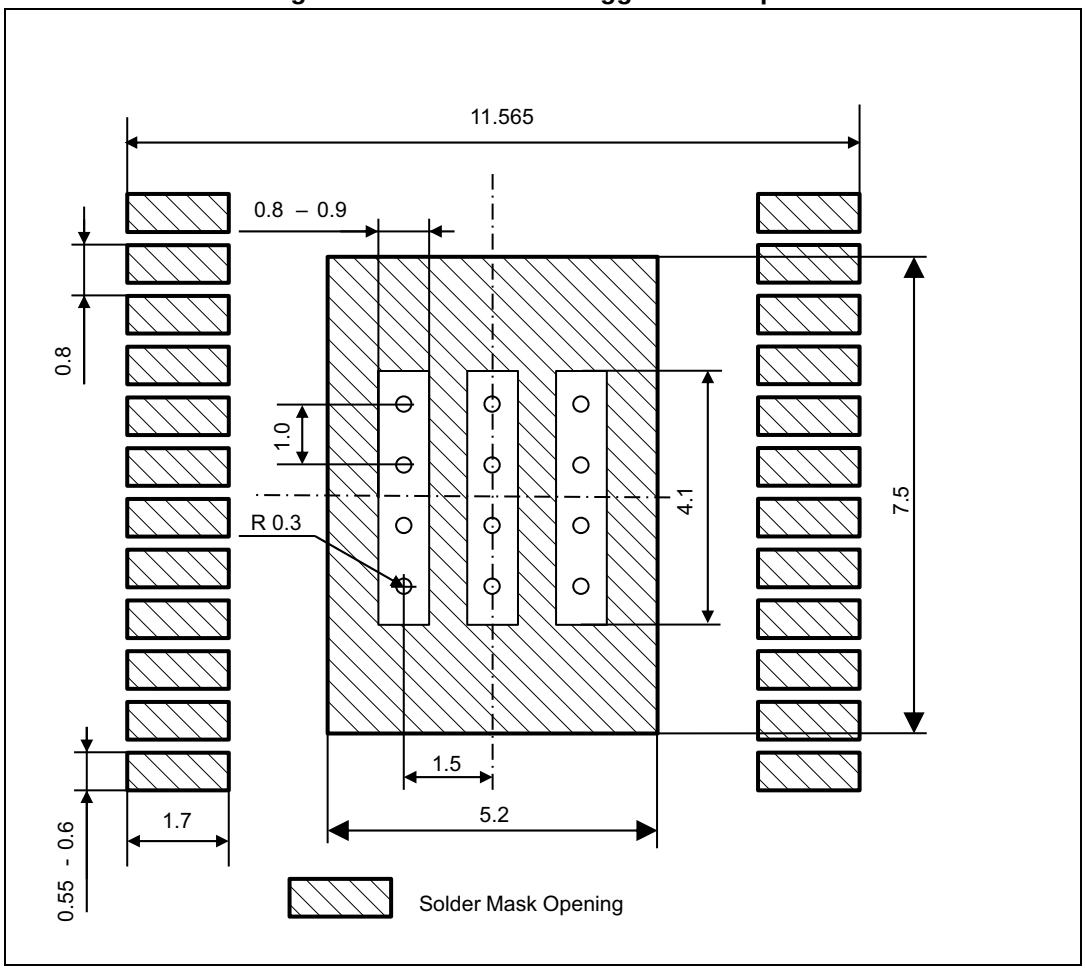


Table 13. PowerSSO-24 tape dimensions

Tape width	W	24
Tape hole spacing	P0 (± 0.1)	4
Component spacing	P	12
Hole diameter	D (± 0.05)	1.55
Hole diameter	D1 (min.)	1.5
Hole position	F (± 0.1)	11.5
Compartment depth	K (max.)	2.85
Hole spacing	P1 (± 0.1)	2

Note: According to the Electronic Industries Association (EIA) standard 481 rev. A, Feb 1986.

Figure 19. VNI4140K-32 suggested footprint



Note: STMicroelectronics is not responsible for any PCB related issues. The footprint shown in the above figure is a suggestion which might not be in line to the customer PCB supplier design rules.

All dimensions are in mm.

13 Ordering information

Table 14. Ordering information

Order codes	Package	Packaging
VNI4140K-32	PowerSSO-24	Tube
VNI4140KTR-32	PowerSSO-24	Tape and reel

14 Revision history

Table 15. Document revision history

Date	Revision	Changes
12-Dec-2011	1	Initial release.
06-Feb-2012	2	Updated I_{lim} minimum value in *Table 8: Protection and diagnostic*. Inserted new feature: ESD according to IEC 61000-4-2 up to +/-25 KV, in cover page.
07-Mar-2012	3	Suggested footprint inserted. In *Table 5.* parameter I_{LGND} has been added.
25-Mar-2013	4	Updated I_{LIM} minimum value in *Table 8*. Minor text changes.
06-Nov-2013	5	Updated E_{AS} value in *Table 2: Absolute maximum ratings*. Added *Figure 14*.
11-Dec-2013	6	Updated *Section 10*.

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